TOSHIBA TRANSISTOR SILICON NPN EPITAXIAL TYPE (PCT PROCESS)

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AUDIO FREQUENCY AMPLIFIER APPLICATIONS. DRIVER STAGE FOR LED LAMP APPLICATIONS. TEMPERATURE COMPENSATION APPLICATIONS.

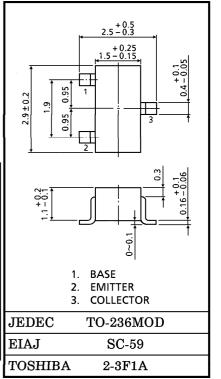
 $h_{FE}(1) = 5000 \text{ (Min.) (IC} = 10 \text{mA)}$ High hFE

 $h_{FE}(2) = 10000 \text{ (Min.)} (IC = 100 \text{mA})$

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	v_{CBO}	40	V
Collector-Emitter Voltage	v_{CEO}	40	V
Emitter-Base Voltage	v_{EBO}	10	V
Collector Current	$I_{\mathbb{C}}$	300	mA
Base Current	$I_{\mathbf{B}}$	60	mA
Collector Power Dissipation	PC	150	mW
Junction Temperature	T_{j}	125	$^{\circ}\mathrm{C}$
Storage Temperature Range	$\mathrm{T_{stg}}$	-55~125	°C

Unit in mm

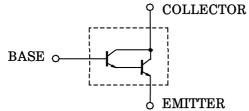


Weight: 0.012g

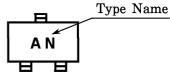
ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	I_{CBO}	$V_{CB} = 40V, I_{E} = 0$	_		0.1	μ A
Emitter Cut-off Current	$I_{ m EBO}$	$V_{EB}=8V$, $I_C=0$	_	1	0.1	μ A
DC Current Gain	h _{FE} (1)	$V_{\text{CE}} = 5V$, $I_{\text{C}} = 10$ mA	5000	1	_	
	h _{FE} (2)	V_{CE} =2V, I_{C} =100mA	10000	I	_	
Collector-Emitter Saturation Voltage	V _{CE (sat)}	$I_{C} = 300 \text{mA}, I_{B} = 0.3 \text{mA}$	_	0.9	1.3	V
Base-Emitter Voltage	$ m V_{BE}$	$V_{CB} = 2V, I_{C} = 100 \text{mA}$	_	1.25	1.6	V

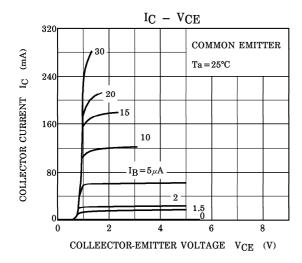
EQUIVALENT CIRCUIT

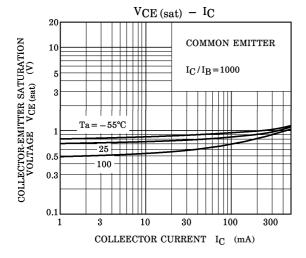


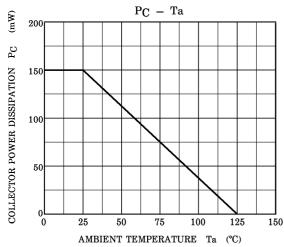


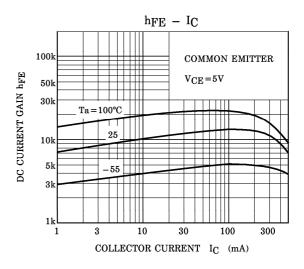


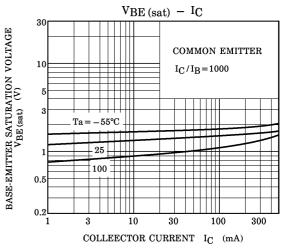
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